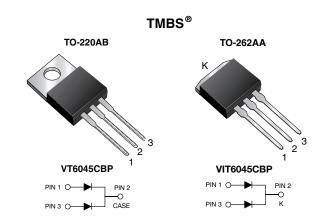


Vishay General Semiconductor

# Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low  $V_F = 0.33 \text{ V}$  at  $I_F = 10 \text{ A}$ 



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 30 A				
V <sub>RRM</sub>	45 V				
I <sub>FSM</sub>	320 A				
V <sub>F</sub> at I <sub>F</sub> = 30 A	0.47 V				
T <sub>OP</sub> max. (AC mode)	150 °C				
T <sub>J</sub> max. (DC forward current)	200 °C				
Package	TO-220AB, TO-262AA				
Diode variation	Dual common cathode				

#### **FEATURES**

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

· High efficiency operation

Solder dip 275 °C max. 10 s, per JESD 22-B106

• T<sub>.I</sub> 200 °C max. in solar bypass mode application

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

## (Pb) BoHS

COMPLIANT HALOGEN FREE

#### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

#### **MECHANICAL DATA**

Case: TO-220AB, TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	VT6045CBP	VIT6045CBP	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	45		V	
Maximum average forward rectified current (fig. 1)	per device	. (1)	60		А	
	per diode	I <sub>F(AV)</sub> <sup>(1)</sup>	30			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	320		А	
Operating junction and storage temperature range (AC mode)		T <sub>OP</sub> , T <sub>STG</sub>	-40 to +150		°C	
Junction temperature in DC forward current without reverse bias, $t \le 1 \text{ h}$		T <sub>J</sub> <sup>(2)</sup>	≤ 2	200	°C	

#### Notes

<sup>(1)</sup> With heatsink

<sup>(2)</sup> Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

# VT6045CBP, VIT6045CBP

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	15 A T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V	
	I <sub>F</sub> = 15 A			0.47	-		
	I <sub>F</sub> = 30 A			0.54	0.64		
	I <sub>F</sub> = 10 A	T <sub>A</sub> = 125 °C		0.33	-		
	I <sub>F</sub> = 15 A			0.37	-		
	I <sub>F</sub> = 30 A			0.47	0.56		
Reverse current per diode	V <sub>R</sub> = 45 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	3000	μΑ	
	v <sub>R</sub> = 45 v	T <sub>A</sub> = 125 °C		18	50	mA	

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VT6045CBP VIT6045CBP		UNIT
Typical thermal resistance	per diode	В	1.5		°C/W
	per device	$ R_{\theta JC}$	0.8		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	VT6045CBP-M3/4W	1.89	4W	50/tube	Tube	
TO-262AA	VIT6045CBP-M3/4W	1.45	4W	50/tube	Tube	

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

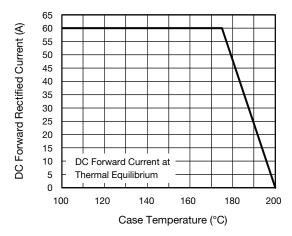
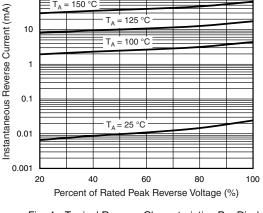


Fig. 1 - Maximum Forward Current Derating Curve



100

Fig. 4 - Typical Reverse Characteristics Per Diode

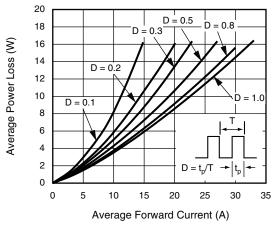


Fig. 2 - Forward Power Loss Characteristics Per Diode

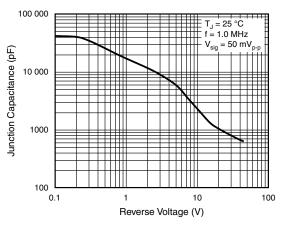


Fig. 5 - Typical Junction Capacitance Per Diode

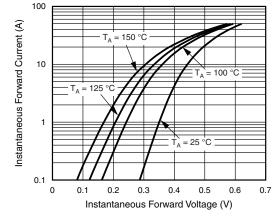


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

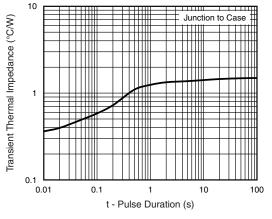
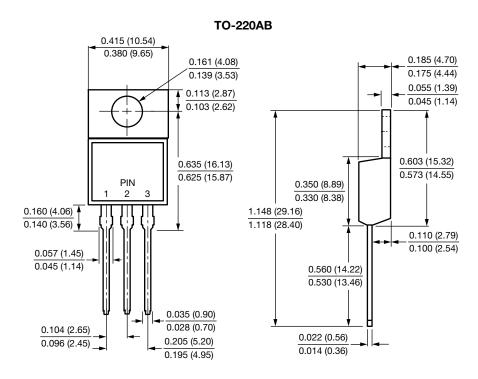


Fig. 6 - Typical Transient Thermal Impedance Per Diode

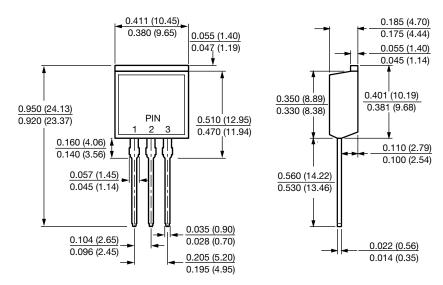


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#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



#### **TO-262AA**





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